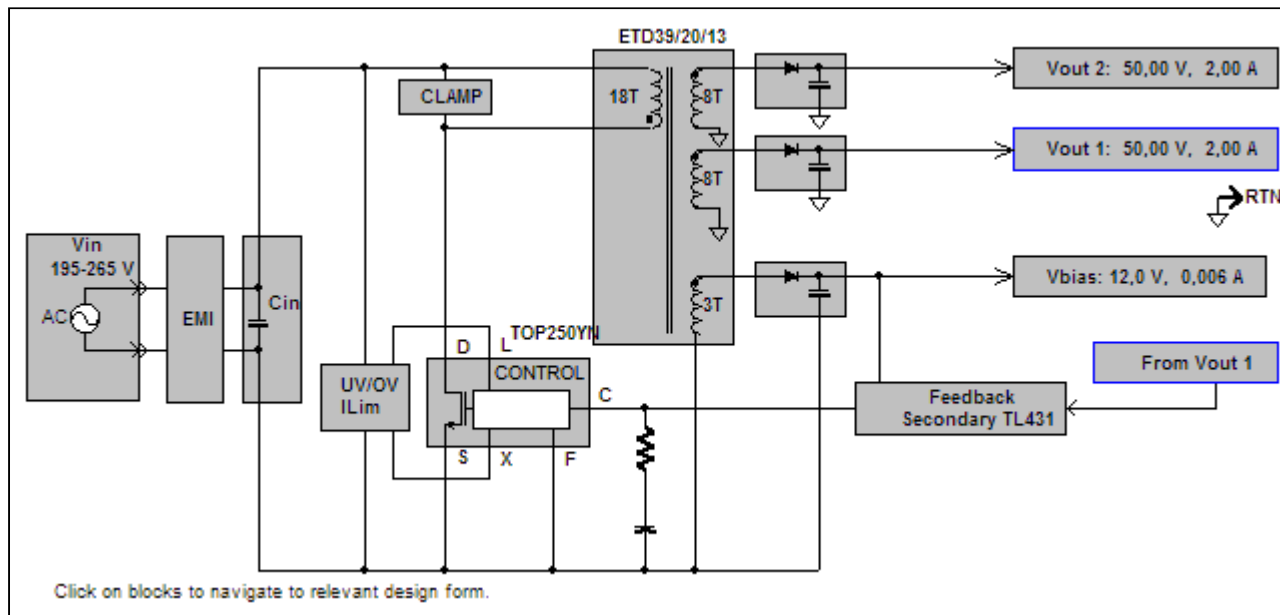




Design Passed (Optimization Done)

Design Report



Design Results

Power Supply Input

Var	Value	Units	Description
VACMIN	195	V	Minimum Input AC Voltage
VACMAX	265	V	Maximum Input AC Voltage
FL	50	Hz	Line Frequency
TC	1,98	ms	Diode Conduction Time
Z	0,63		Loss Allocation Factor
η	82,0	%	Efficiency Estimate
I _{AVG}	1,05	A	Average Diode Bridge Current
Input Rectifier	1N5408		Recommended Input Diodes
V _{MIN}	233,0	V	Minimum DC Input Voltage
V _{MAX}	374,8	V	Maximum DC Input Voltage

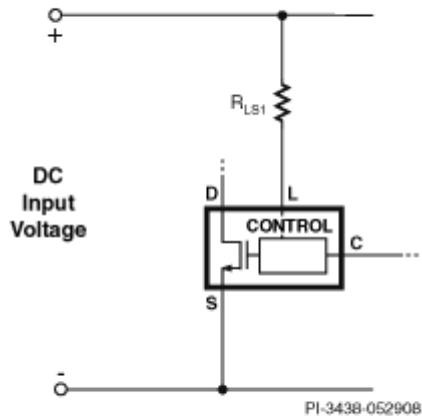
EMI Filter

Var	Value	Units	Description
CIN1	180,00	μ F	Input Bulk Capacitor
LCM	6,00	mH	Common Mode Choke
CX	0,10	μ F	X Capacitor

Device Variables

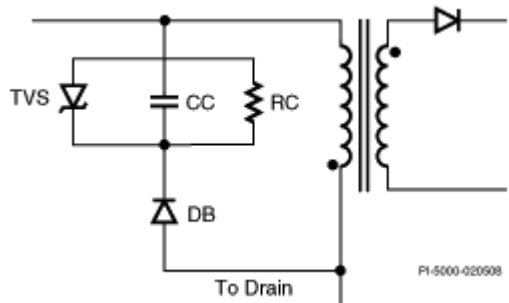
Var	Value	Units	Description
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Device	TOP250YN		PI Device Name
PO	200,07	W	Total Output Power
VDRAIN Estimated	586,03	V	Actual Estimated Drain Voltage
VDS	11,89	V	On state Drain to Source Voltage
FS	132000	Hz	Switching Frequency
KP	0,88		Continuous/Discontinuous Operating Ratio
KI	1,00		Current Limit Reduction Factor
ILIMITEXT	5,86	A	Programmed Current Limit
ILIMITMIN	5,86	A	Current Limit Minimum
ILIMITMAX	6,74	A	Current Limit Maximum
IP	5,61	A	Peak Primary Current (at VMIN)
IRMS	1,99	A	Primary RMS Current (at VMIN)
P_NO_LOAD	500	mW	Estimated No Load Input Power
DMAX	0,33		Maximum Duty Cycle
RLS	4,7	MΩ	Line sense resistor



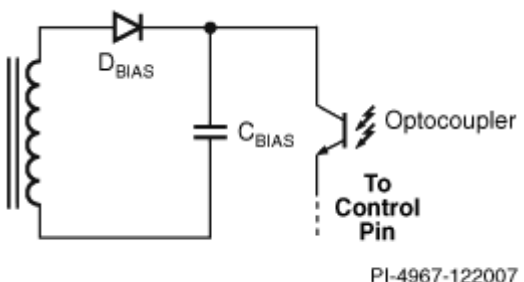
Clamp Components

Var	Value	Units	Description
DB	FR257		Recommended Blocking Diode
RC	9,10	kΩ	Clamping resistor
CC	8,200	nF	Clamp Capacitor
VCLAMP	173,79	V	Estimated average clamping voltage
VRZ	P6KE200A		Recommended Zener Clamp
Clamp Loss	3,32	W	Clamp Dissipation



Bias Variables

Var	Value	Units	Description
VB	12,0	V	Bias Voltage
IB	0,006	A	Bias Current
VDB	0,95	V	Bias Diode Forward Voltage Drop
PIVB	78	V	Bias Rectifier Max Peak Inverse Voltage



NB	3		Bias Winding Number of Turns
Wire Size	25	AWG	Wire size of Bias windings
Winding Type	Bifilar (x2)		Wire type of Bias windings
Layers	0,12		Bias Winding Layers
Start Pin(s)	6		Starting pin(s) for Bias winding
Termination Pin(s)	5		Termination pin(s) for Bias winding

Transformer Construction Parameters

Var	Value	Units	Description
Core Type	ETD39/20/13		Core Type
Core Material	NC-2H (Nicera) or Equivalent		Core Material
Bobbin Reference	Generic, 8 pri. + 8 sec.		Bobbin Reference
Bobbin Orientation	Horizontal		Bobbin type
Primary Pins	6		Number of Primary pins used
Secondary Pins	4		Number of Secondary pins used
LP	111	µH	Primary Inductance
NP	17,0		Calculated Primary Winding Total Number of Turns
NSM	8		Secondary Main Number of Turns
CMA	647	Cmils/A	Primary Winding Current Capacity
VOR	110,00	V	Reflected Output Voltage
BW	25,70	mm	Bobbin Winding Width
ML	0,00	mm	Safety Margin on Left Width
MR	0,00	mm	Safety Margin on Right Width
FF	56	%	Actual Transformer Fit Factor. 100% signifies fully utilized winding window
AE	125,00	mm ²	Core Cross Sectional Area
ALG	384	nH/T ²	Gapped Core Effective Inductance
BM	2933	Gauss	Maximum Flux Density
BP	3521	Gauss	Peak Flux Density
BAC	1286	Gauss	AC Flux Density for Core Loss
LG	0,348	mm	Estimated Gap Length
L_LKG	1,8	µH	Primary Leakage Inductance
LSEC	20	nH	Secondary Trace Inductance

Primary Winding Section 1

Var	Value	Units	Description
NP1	9		Rounded (Integer) Number of Primary winding turns in the first section of primary
Wire Size	24	AWG	Wire size of primary winding
Winding Type	Trifilar (x3)		Primary winding number of parallel wire strands
L	0,60		Primary Number of Layers
DC Copper Loss	0,05	W	Primary DC Losses
PIN_S	4		Starting pin(s) for first section of primary winding
PIN_T	2,3		Termination pin(s) for first section of primary winding

Primary Winding Section 2

Var	Value	Units	Description
NP2	9		Rounded (Integer) Number of Primary winding turns in the second section of primary
Wire Size	24	AWG	Wire size of primary winding
Winding Type	Trifilar (x3)		Primary winding number of parallel wire strands
L2	0,60		Primary Number of Layers in 2nd split winding
DC Copper Loss	0,08	W	Primary 2 DC Losses
PIN_S2	2,3		Starting pin(s) for the second section of primary winding
PIN_T2	1		Termination pin(s) for the second section of primary winding

▼ **Output 1**

Var	Value	Units	Description
VO	50,00	V	Output Voltage
IO	2,00	A	Output Current
VOUT_ACTUAL	50,00	V	Actual Output Voltage
NS	8		Secondary Number of Turns
Wire Size	25	AWG	Wire size of secondary winding
Winding Type	Bifilar (x2)		Output winding number of parallel strands
L_S_OUT	0,40		Secondary Output Winding Layers
DC Copper Loss	0,26	W	Secondary DC Losses
Start Pin(s)	10		Starting pin(s) for Output winding
Termination Pin(s)	9		Termination pin(s) for Output winding
VD	1,70	V	Output Winding Diode Forward Voltage Drop
PIVS	217	V	Output Rectifier Maximum Peak Inverse Voltage
ISP	5,97	A	Peak Secondary Current
ISRMS	3,00	A	Secondary RMS Current
DO	UF5404		Recommended Output Diode
CO	680 x 1	µF	Output Capacitor
IRIPPLE	2,24	A	Output Capacitor RMS Ripple Current
Expected Lifetime	84180	hr	Expected Lifetime of Output Capacitor
LPF	2,2 - 10	µH	Post Filter Inductor
CPF	100 - 680	µF	Post Filter Capacitor

▼ **Output 2**

Var	Value	Units	Description
VO	50,00	V	Output Voltage
IO	2,00	A	Output Current
VOUT_ACTUAL	50,00	V	Actual Output Voltage
NS	8		Secondary Number of Turns
Wire Size	25	AWG	Wire size of secondary winding
Winding Type	Bifilar (x2)		Output winding number of parallel strands
L_S_OUT	0,40		Secondary Output Winding Layers
DC Copper Loss	0,29	W	Secondary DC Losses
Start Pin(s)	12		Starting pin(s) for Output winding
Termination Pin(s)	11		Termination pin(s) for Output winding
VD	1,70	V	Output Winding Diode Forward Voltage Drop
PIVS	217	V	Output Rectifier Maximum Peak Inverse Voltage
ISP	5,97	A	Peak Secondary Current
ISRMS	3,00	A	Secondary RMS Current
DO	UF5404		Recommended Output Diode
CO	680 x 1	µF	Output Capacitor
IRIPPLE	2,24	A	Output Capacitor RMS Ripple Current

Expected Lifetime	84180	hr	Expected Lifetime of Output Capacitor
LPF	2,2 - 10	μH	Post Filter Inductor
CPF	100 - 680	μF	Post Filter Capacitor

Feedback Circuit

Var	Value	Units	Description
RF1	11,30	kΩ	Feedback Resistor to bias the error Amplifier
RF2	215,00	kΩ	Compensation resistor See Information section for detail
RF3	976,00	Ω	Gain limiting Resistor
RF5	6,81	Ω	TOPSwitch Control Pin Resistor
CF1	15,00	nF	Compensation Capacitor
CF3	47,00	μF	TOPSwitch Control Pin Capacitor
Opto CTR	80,00		Optocoupler Current Transfer Ratio
Error Amp Gain	55,00	dB	Error Amplifier Open Loop Gain
PM	97,21	Deg	Estimated Phase Margin
FC_ACTUAL	1020,7	Hz	Estimated Crossover Frequency

PI-4387-071906

The regulation and tolerances do not account for thermal drifting and component tolerance of the output diode forward voltage drop and voltage drops across the LC post filter. The actual voltage values are estimated at full load only.

Please verify cross regulation performance on the bench.

Errors, Warnings, Information

Description	Fix	Show me	Ref. #
Drain voltage close to BVDS at maximum OV threshold.	Verify BVDS during line surge, decrease VUVON_MAX or reduce VOR.		237
Resistor value is too large and may not provide enough bias for error amplifier. Decrease Resistor.	Decrease RF2		606